

MDL-III-785-Lock/1~600mW



INFRARED DIODE LASER AT 785nm

It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are specially designed for Raman spectroscopy, measurement, communication, spectrum analysis, etc.

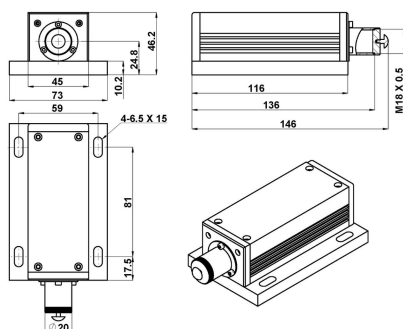


SPECIFICATIONS

Central wavelength (nm)	785±0.5	
Operating mode	CW	
Output power (mW)	>1, 50, 100, ... ,600	
Power stability (rms, over 4 hours)	<3%, <2%, <1%	
Transverse mode	Multimode	
Spectral line width(nm)	0.2 (0.1, 0.06 optional)	
Dimensions of beam at the aperture (mm)	~10×1	
Beam divergence, full angle (mrad)	<3. 0	
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	24. 8	
Operating temperature (°C)	10~35	
Power supply	85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)
	100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional	
Expected lifetime (hours)	10000	
Warranty	1 year	

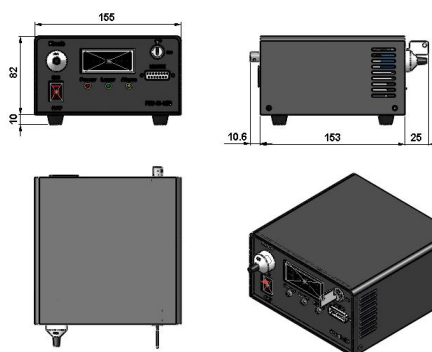


MDL-III-785-Lock



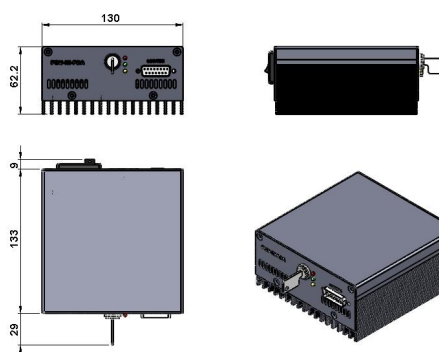
146 (L) ×73(W) ×46.2 (H) mm³, 0.7kg

PSU-III-LED



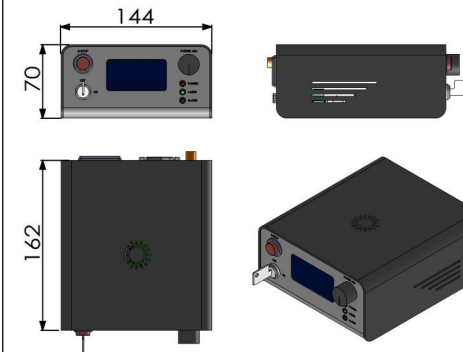
188.6 (L) ×155(W) ×92 (H) mm³, 1.5kg

PSU-III-FDA



171(L) ×130(W) ×62.2 (H) mm³, 1.2kg

PSU-A-D



162(L) ×144(W) ×70 (H) mm³, 1.0kg